

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

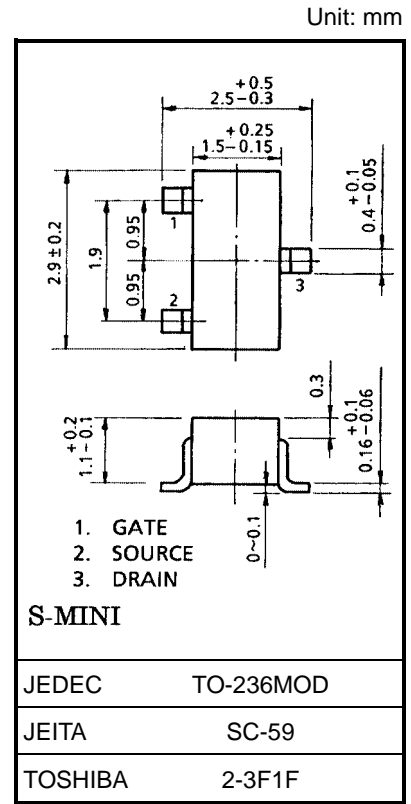
SSM3K01F

High Speed Switching Applications

- Small package
- Low on resistance: Ron = 120 mΩ (max) (VGS = 4 V)
: Ron = 150 mΩ (max) (VGS = 2.5 V)
- Low gate threshold voltage: Vth = 0.6~1.1 V (VDS = 3 V, ID = 0.1 mA)

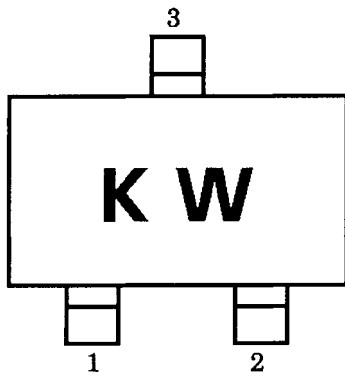
Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DS}	30	V
Gate-source voltage		V _{GSS}	±10	V
Drain current	DC	I _D	1.3	A
	Pulse	I _{DP}	2.6	
Drain power dissipation		P _D	200	mW
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55~150	°C

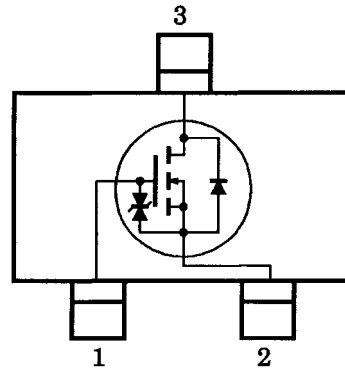


Weight: 0.012 g (typ.)

Marking



Equivalent Circuit



Handling Precaution

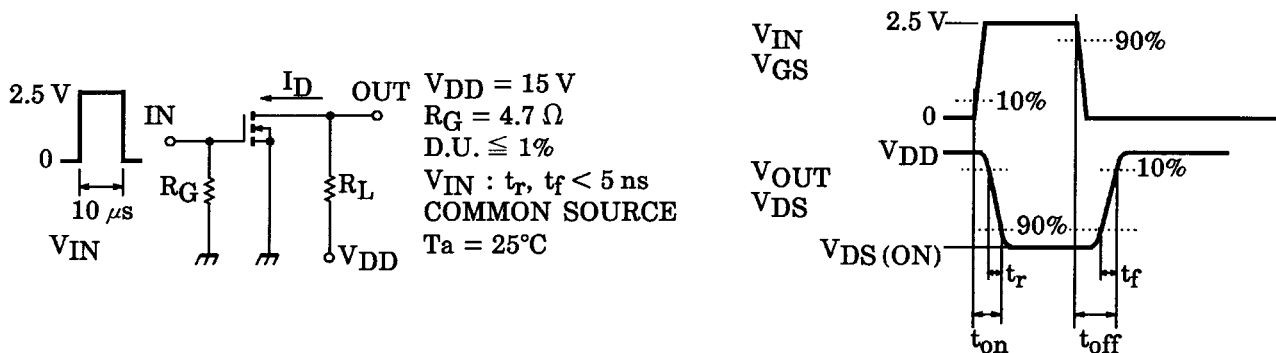
When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 10\text{ V}, V_{DS} = 0$	—	—	± 5	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 1\text{ mA}, V_{GS} = 0$	30	—	—	V
Drain cut-off current		I_{DSS}	$V_{DS} = 30\text{ V}, V_{GS} = 0$	—	—	1	μA
Gate threshold voltage		V_{th}	$V_{DS} = 3\text{ V}, I_D = 0.1\text{ mA}$	0.6	—	1.1	V
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 3\text{ V}, I_D = 0.65\text{ A}$ (Note)	2.0	—	—	S
Drain-source ON resistance		$R_{DS(ON)}$	$I_D = 0.65\text{ A}, V_{GS} = 4\text{ V}$ (Note)	—	85	120	m Ω
			$I_D = 0.65\text{ A}, V_{GS} = 2.5\text{ V}$ (Note)	—	115	150	
Input capacitance		C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	152	—	pF
Reverse transfer capacitance		C_{rss}	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	41	—	pF
Output capacitance		C_{oss}	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	102	—	pF
Switching time	Turn-on time	t_{on}	$V_{DD} = 15\text{ V}, I_D = 0.5\text{ A}, V_{GS} = 0\sim 2.5\text{ V}, R_G = 4.7\ \Omega$	—	45	—	ns
	Turn-off time	t_{off}		—	69	—	

Note: Pulse test

Switching Time Test Circuit



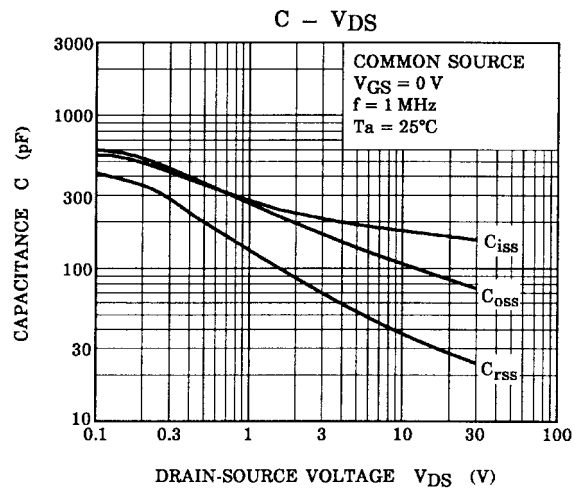
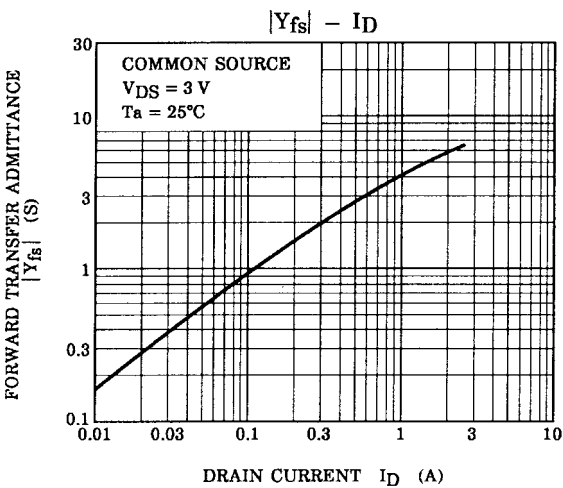
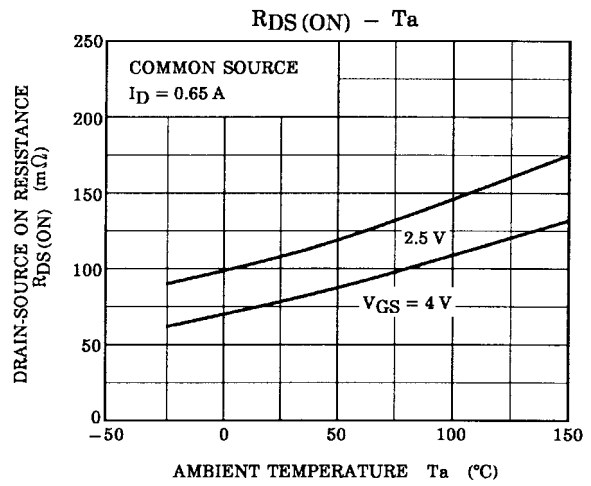
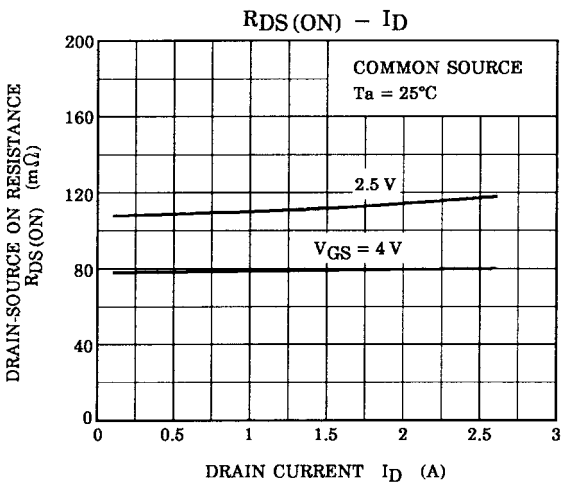
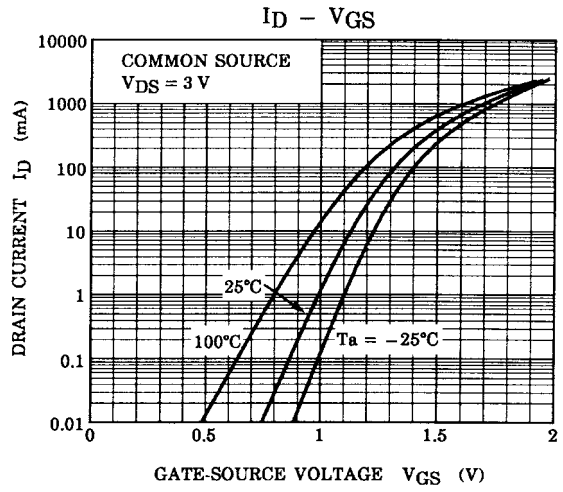
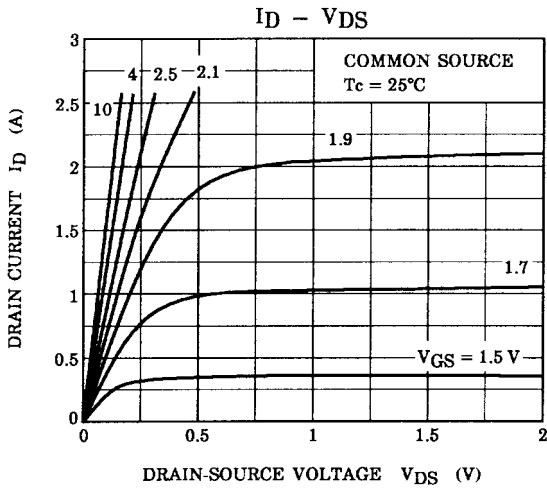
Precaution

V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = 100\ \mu\text{A}$ for this product. For normal switching operation, $V_{GS(ON)}$ requires higher voltage than V_{th} and $V_{GS(off)}$ requires lower voltage than V_{th} .

(Relationship can be established as follows: $V_{GS(off)} < V_{th} < V_{GS(ON)}$)

Please take this into consideration for using the device.

V_{GS} recommended voltage of 2.5 V or higher to turn on this product.



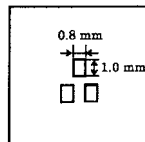
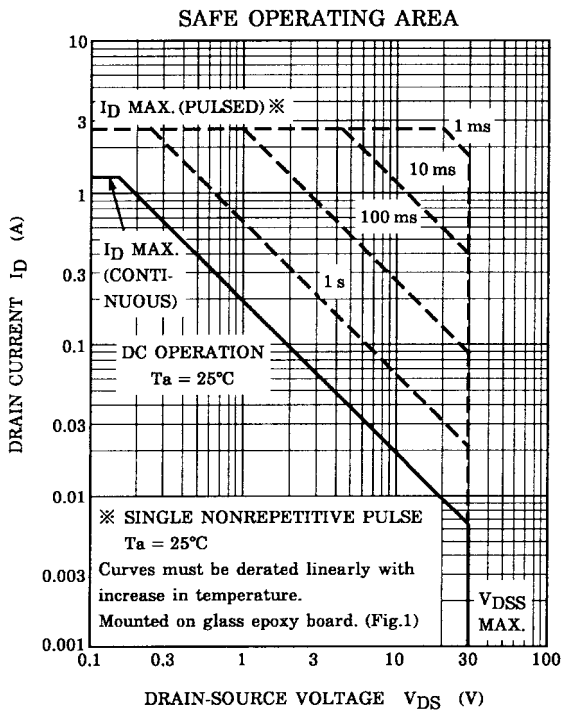
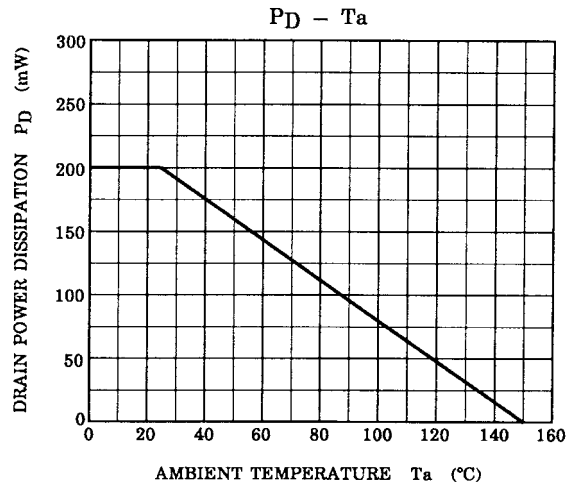
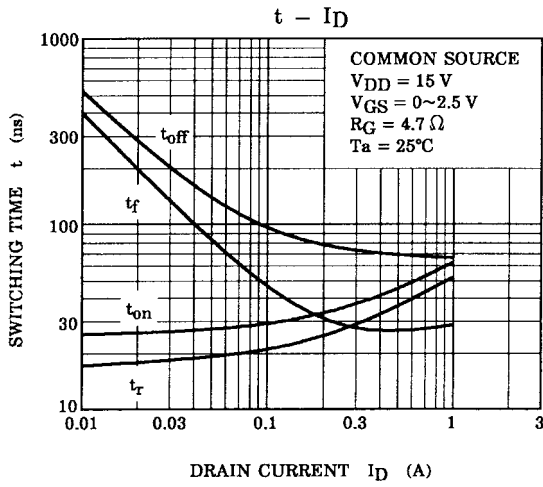


Figure 1 25.4 mm × 25.4 mm × 1.6 t (a Cu pad of 0.8 mm² area)

RESTRICTIONS ON PRODUCT USE

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